

8th ESA Round Table on MNT for Space Application, Noordwijk



Heterogeneous Technology Alliance

The SOI MEMS Platform: HTA one-stop-shop for microsystems processing

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csem

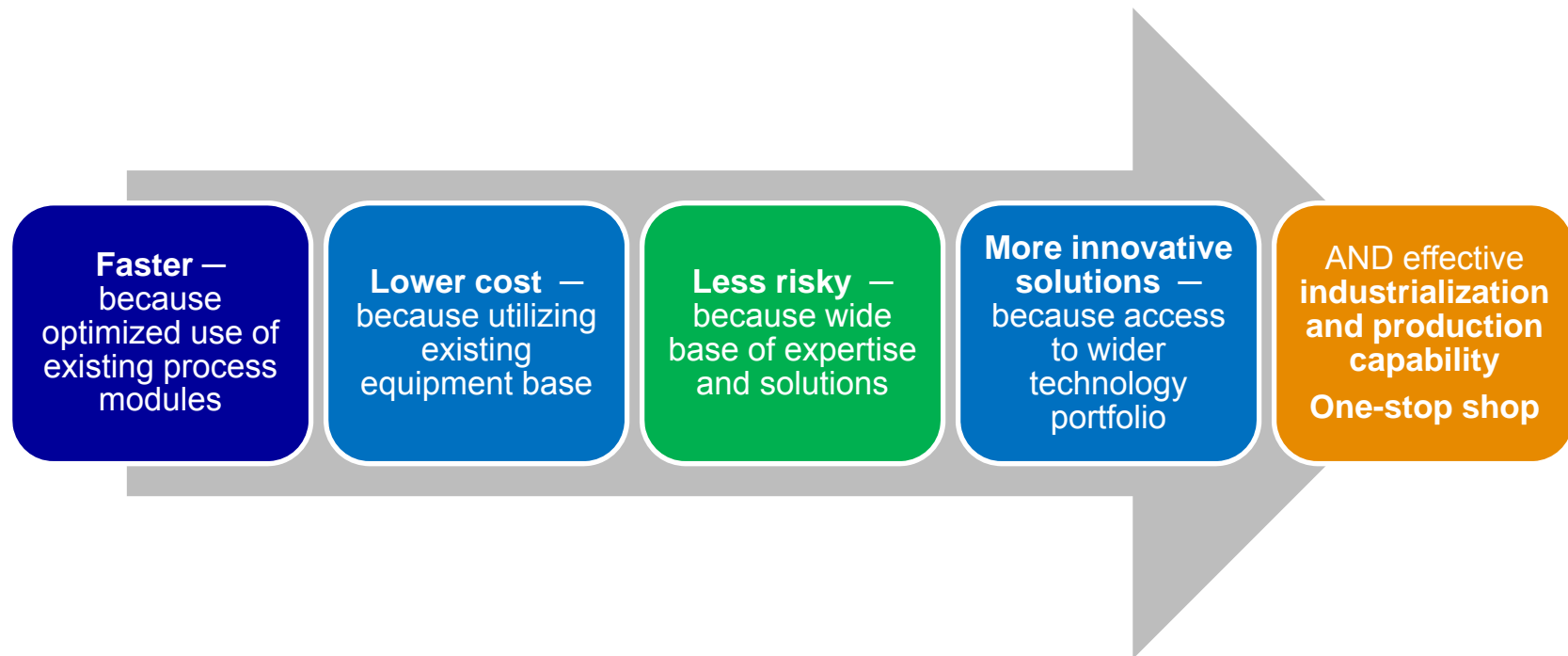
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Added value of HTA MEMS Platform to customers





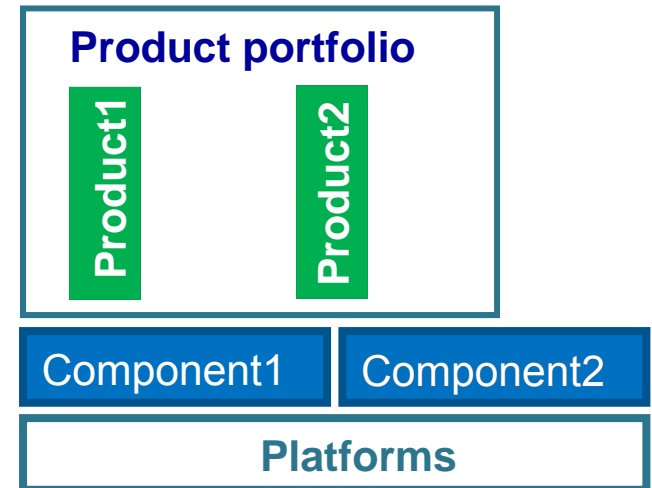
Attractive offering of HTA MEMS Platform One-stop shop

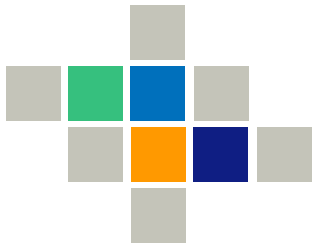
- 1 Very extensive R&D resources, **900 researchers**
- 2 Can provide **prototyping and process development**
- 3 **Industrialization** — bridging the gap between prototyping and production
- 4 Large set of **process modules**
- 5 Large set of **SOI MEMS devices** in offering
- 6 Large set of **processing equipment with back-up/second source options**



Platform purpose and definition

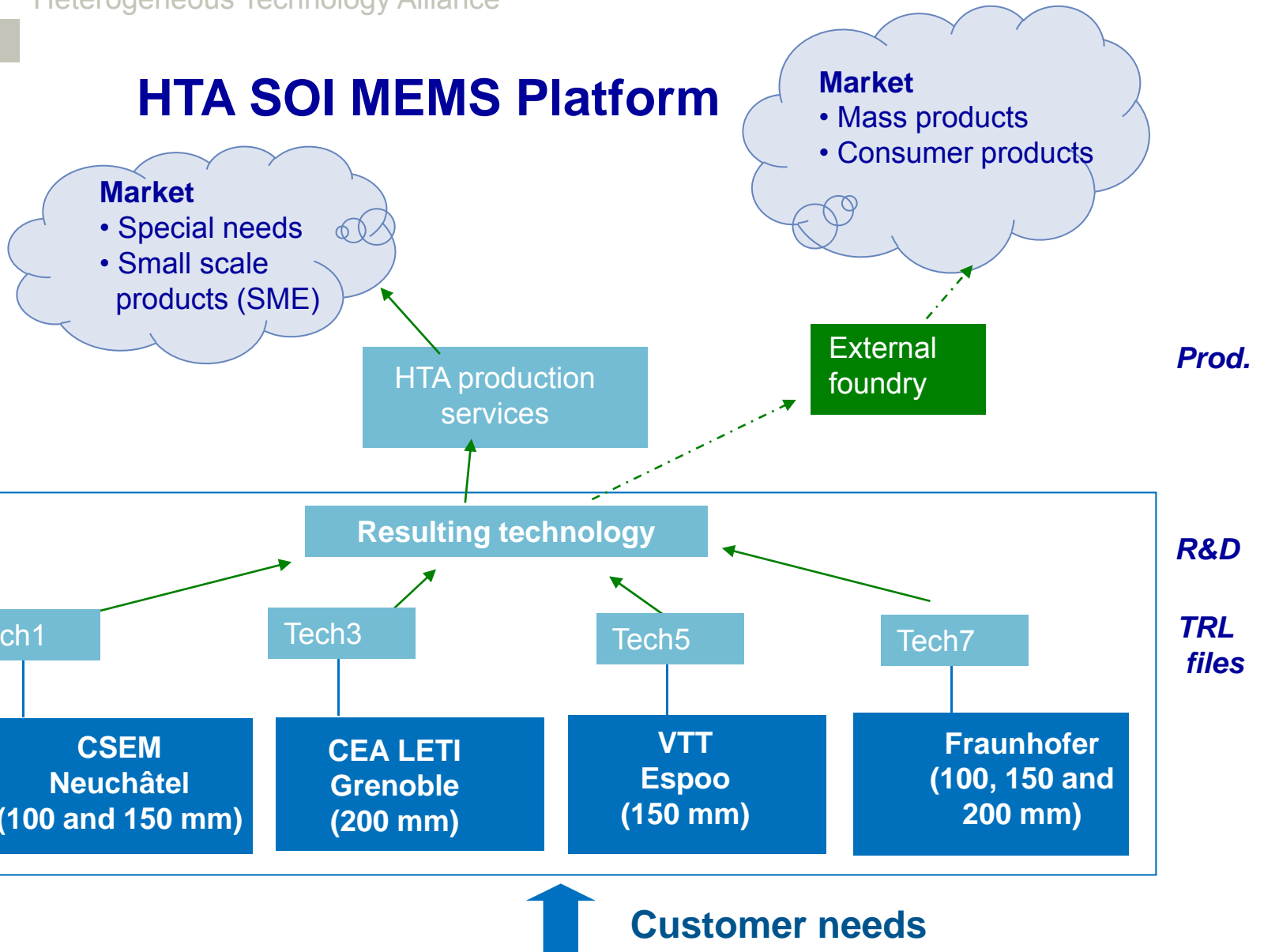
- **Platform purpose**
 - To **create flexibility in designing and manufacturing** new components
 - **Customer needs can be better met** through joining our arsenal of capabilities
 - Open up our arsenal to all HTA partners
- **Definition**
 - Platform composes of **process equipment, steps, modules and needed personnel** of HTA partners
 - Platform **forms a basis for research and product development**
 - Platform **enables flexible processing** capability and prototyping





Heterogeneous Technology Alliance

HTA SOI MEMS Platform





HTA Complete Offer

Integrated solutions

MEMS Platform

- **Design**
 - IC
 - RF
 - MEMS
 - 3D
 - System
- **System building**
- **Testing & reliability**

- **Other Processing**
 - CMOS
 - Roll-to-roll
 - Laser machining
 - Polymer electronics

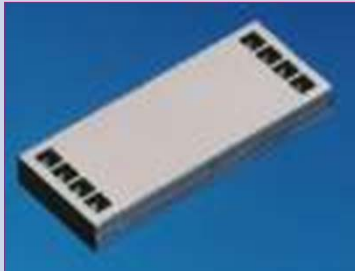
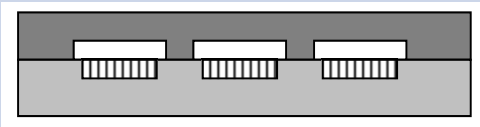
- **Packaging & 3D-Integration**
 - Wafer-level
 - Chip-level
 - LTCC
 - Flexible substrates
 - Polymers

- HTA complete offer covers all key competencies to create solutions for our customers
- Key mission of HTA is to enable flexible integration and combination of different micro- and nanotechnologies
- SOI MEMS Platform managers offer a communication channel between the partners



MEMS Packaging

Wafer Level Packaging



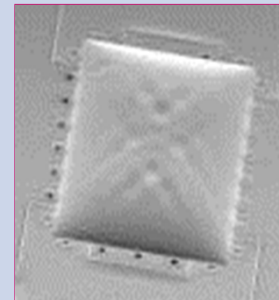
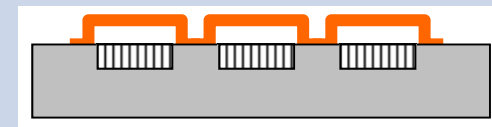
Accelerometer with hermetic cap (Anodic bonding)



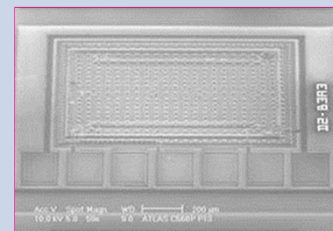
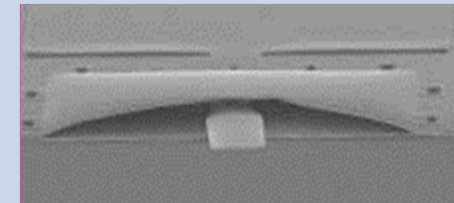
RF Mems with 50 μm silicon cap (polymer bonding)

- Polymer Bonding
- Silicon direct bonding
- Anodic Bonding
- AuSi eutectic bonding
- AuSn eutectic bonding

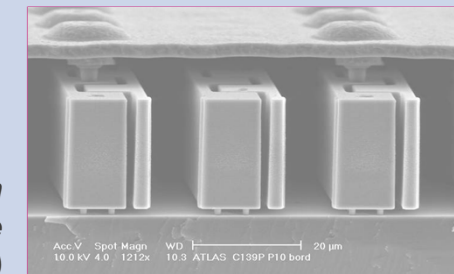
Thin Film Packaging



RF Mems with thin film protection (polymer sacrificial layer)



Accelerometer with hermetic TFP (oxide sacrificial layer)





Packaging and Assembly - label for transport monitoring

The label components:

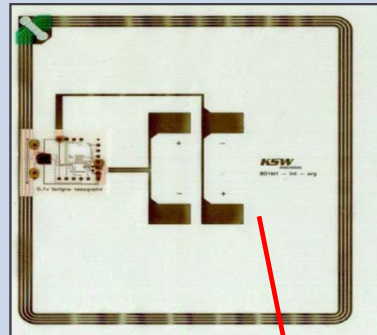
- RF-chip with antenna
- battery for energy supply
- sensor system consisting of the micromechanical transducer and the signal processing electronic

The system has to detect and record inclination and mechanical shock

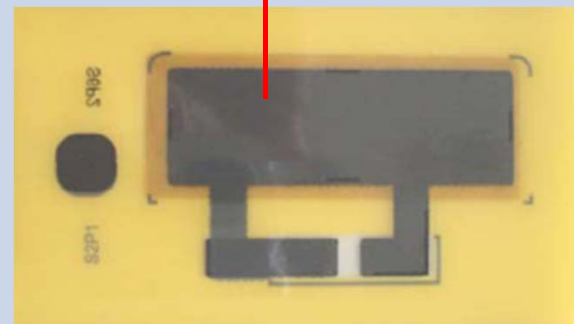
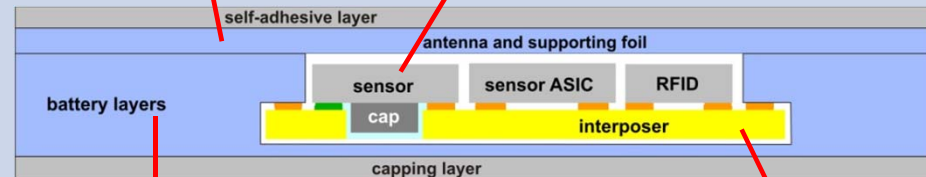
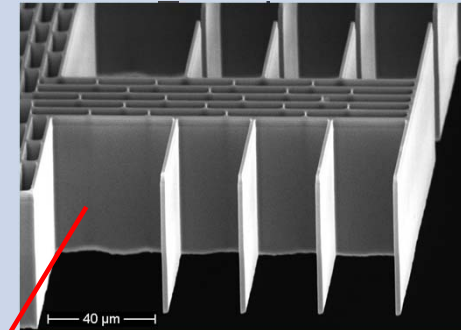


Transport label

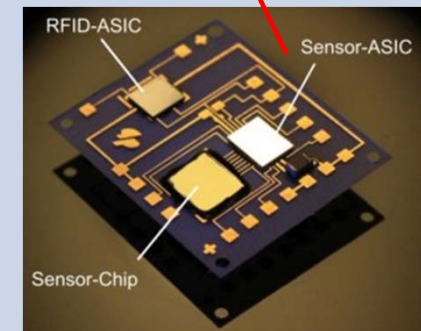
Interposer with dies



Capacitive MEMS



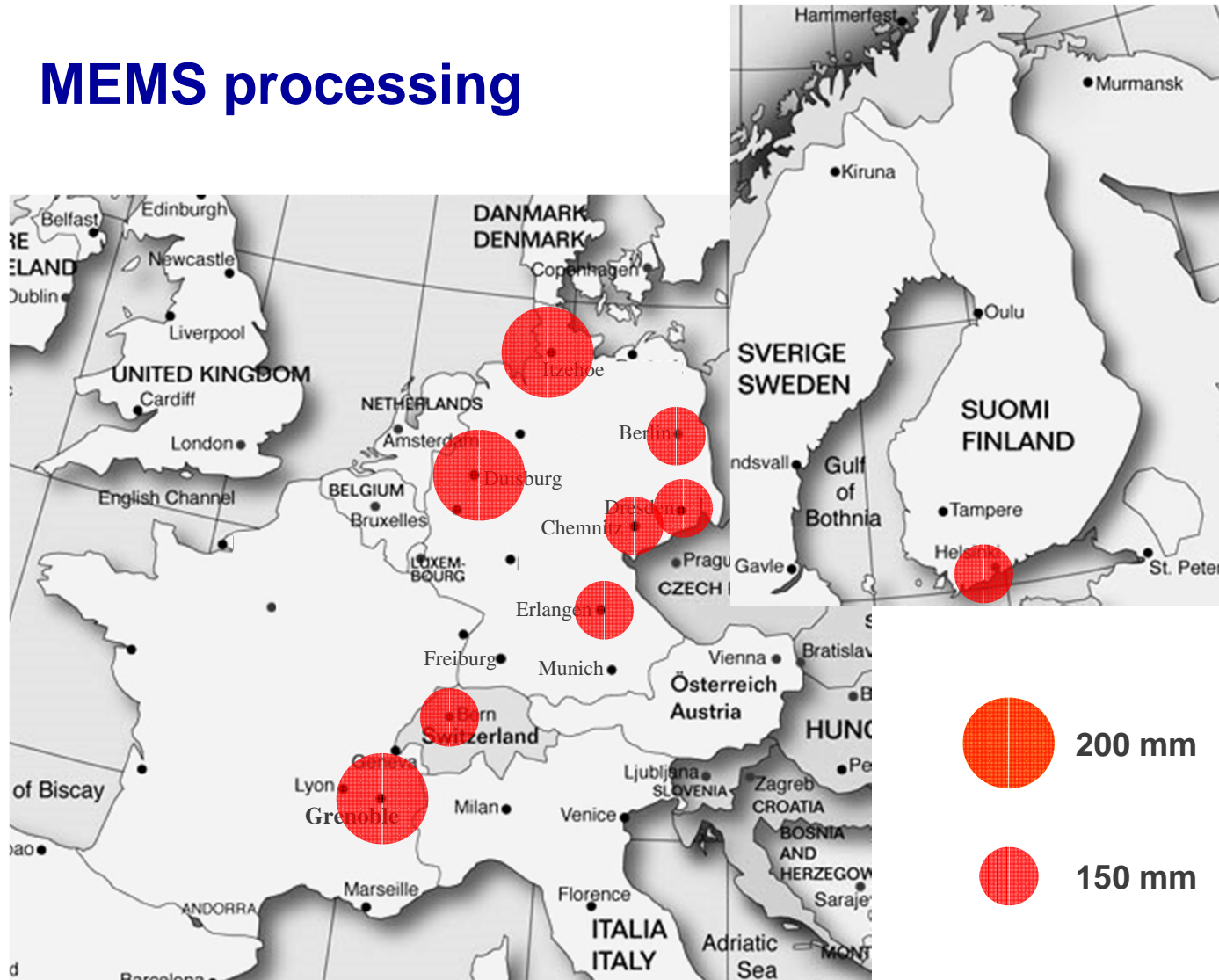
Battery



Antenna with interposer





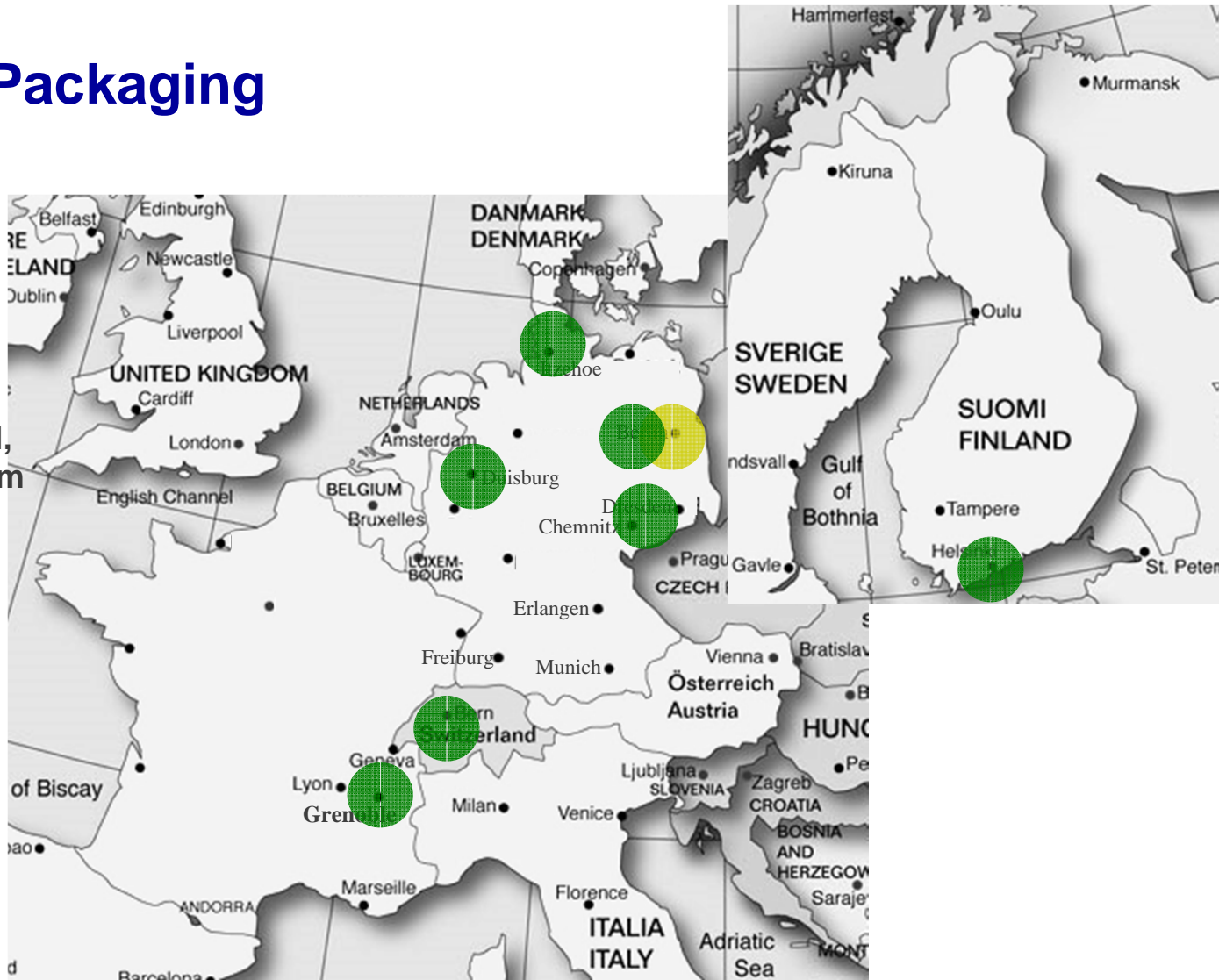
MEMS processing





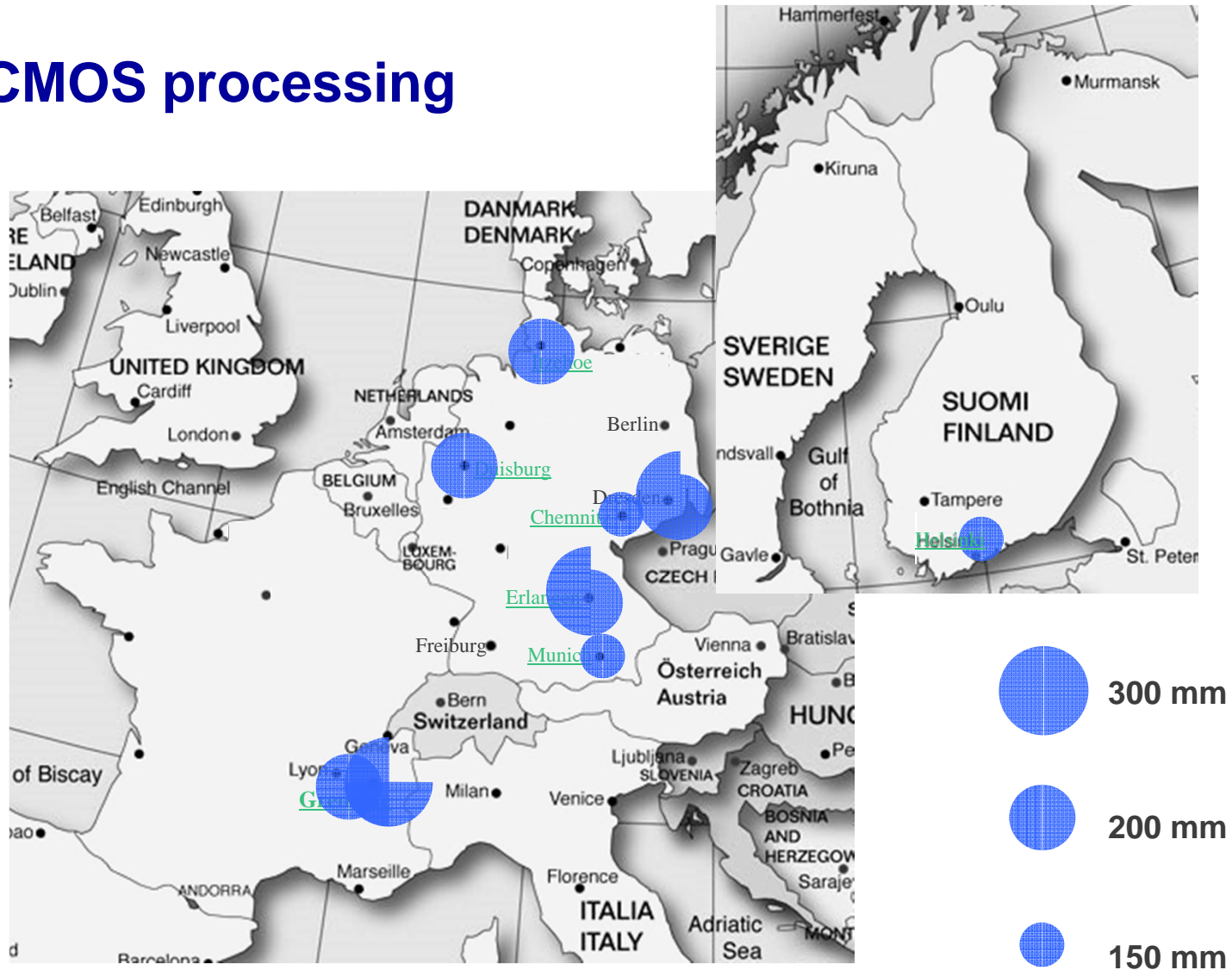
Packaging

-  Wafer-level, 100~200 mm
-  Plastic





CMOS processing





Process steps and equipment list

Name of institute:
Responsible person:
Contact:
Special feature:

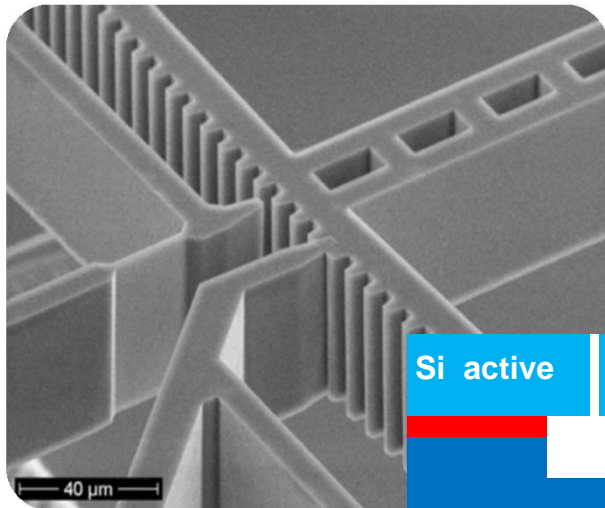
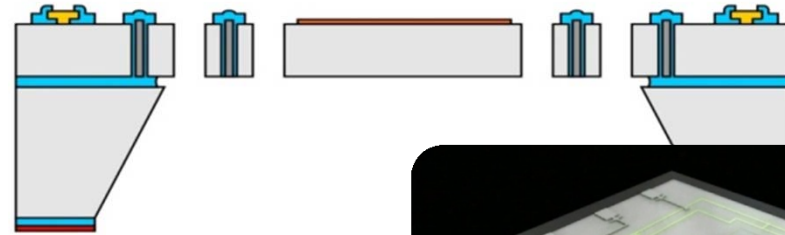
- Example page of process step and equipment list to facilitate quick and efficient response
- Access available through each partner

Applicable materials in MEMS fabrication facility	Chip-Level	100 mm Wafer-Level	150 mm Wafer-Level
Silicon	x	x	x
Glass	x	x	x
Ceramics (i.e. PZT, LTCC,...)	x	x	
Lithium Niobate / Lithium Tantalate	x	x	
others	Sapphire, SiC, Ge	2" wafer Sapphire, SiC, Ge	

Front-End-of-Line	Availability for different substrates and nar					
	Chip-Level		100 mm Wafer-Level		150 mm Wafer-Level	
	©/x/n	name of equipment	©/x/n	name of equipment	©/x/n	name of equipment
RCA clean 1 & 2	x	beaker	x	Arias	x	Arias
Piranha clean	x	beaker	x	beaker	x	beaker
DI-H ₂ O flushing	x	beaker	x	Arias	x	Arias
Thermal Oxidation	0					
dry			x	CentroTherm	x	CentroTherm
wet			x	CentroTherm	x	CentroTherm
RTA			x	Heatpulse 610	x	Heatpulse 610
Chemical Vapour Deposition - CVD						
SiO ₂ - low pressure			x	LPT	x	LPT
SiO ₂ - plasma enhanced			x	P5000 / Oxford	x	P5000 / Oxford
Si ₃ N ₄			x	LPT	x	LPT
Si ₃ N ₄ - plasma enhanced			x	P5000 / Oxford	x	P5000 / Oxford
poly-Si			x	LPT	x	LPT
SiON - plasma enhanced						
TEOS - plasma enhanced						
alpha-Si - plasma enhanced						



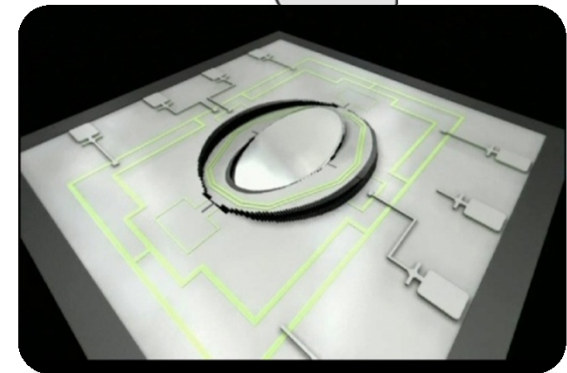
MEMS Device examples from the Platform



Si active

Si basic

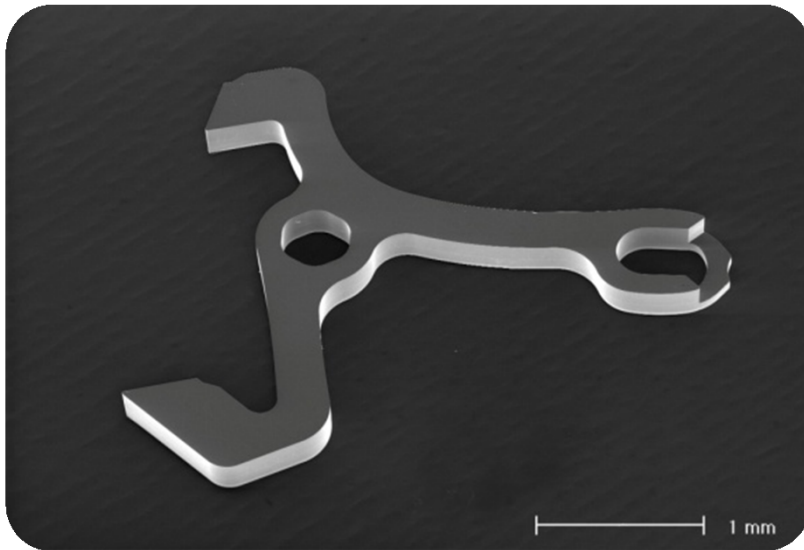
Step-by-step switch-gear
(FhG ENAS Chemnitz)



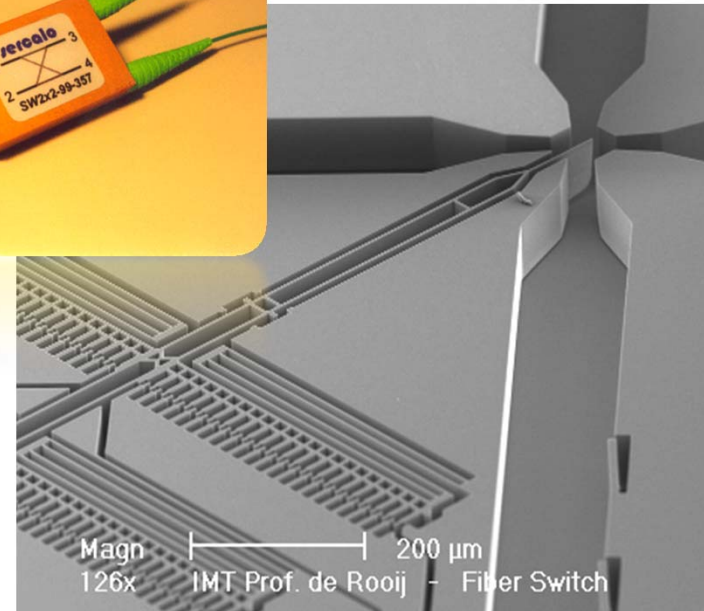
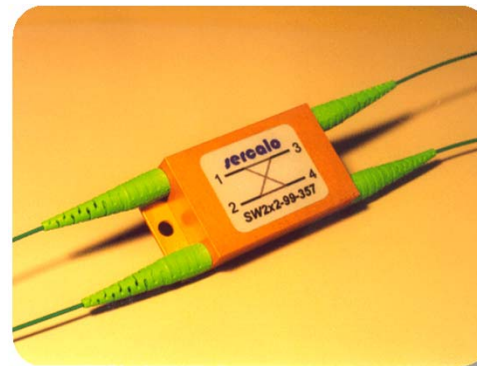
SOI processing of 2D MEMS scanner
(FhG IPMS Dresden)



MEMS Device examples from the Platform



- Precision micromechanical parts
- Production for several watchmakers

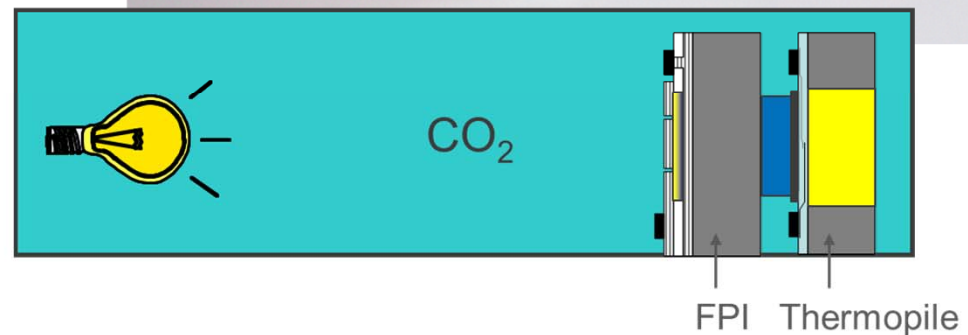
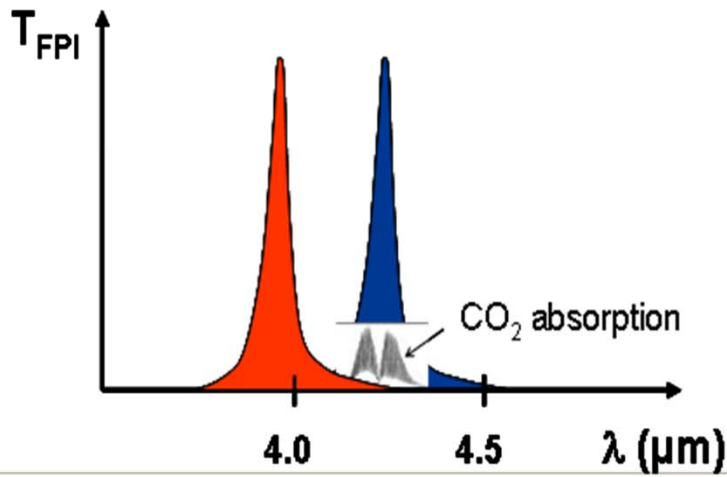


- Micromirror
- Commercialized by Sercalo

MEMS Device examples from the Platform

Example: CO₂ sensor of Vaisala's CARBOCAP

- CARBOCAP[®] sensor for carbon dioxide measurement
- MEMS-chips have been manufactured at VTT's facilities since 1997



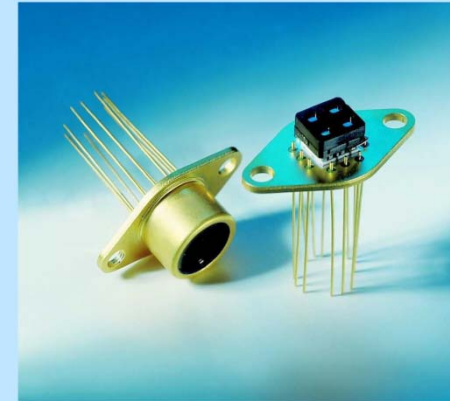


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MEMS Device examples from the Platform

Fuel quality sensor technology

- MEMS is heart of the sensor, including e.g.:
 - Fabry-Perot interferometer
 - Thermopile detector
- The outcome of the VTT's subproject is a mini spectrometer for near infrared wavelength region
 - Optical resolution 5...10 nm
 - Tuning range: 25% of the selected center wavelength



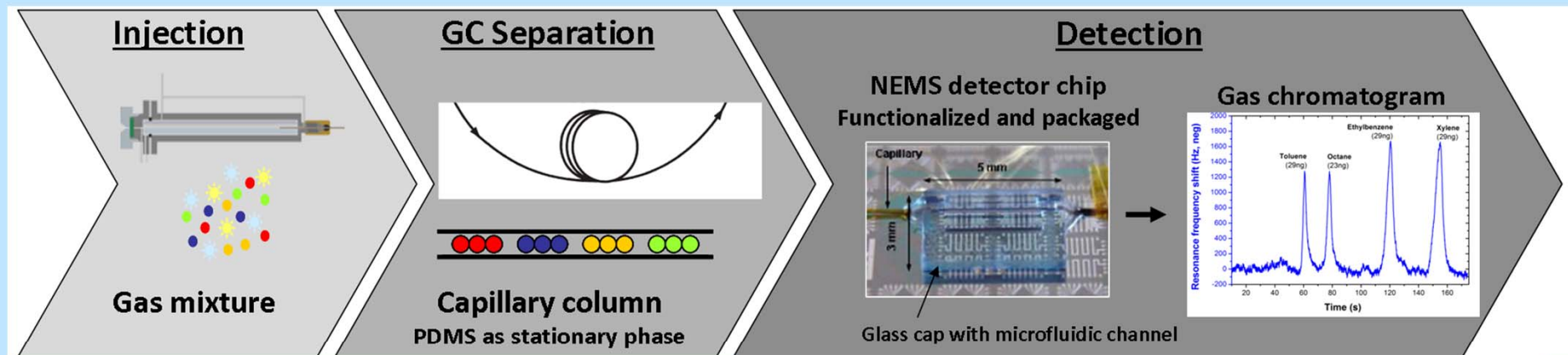
EUREKA/Euripides project **IQFUEL**, Industrial and research partners:
*Continental, PSA Peugeot-Citroen, VTI Technoogies, Selmic, Aboard Engineering
Ensiatec, CEA LETI, IFP*



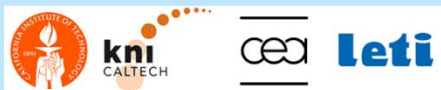
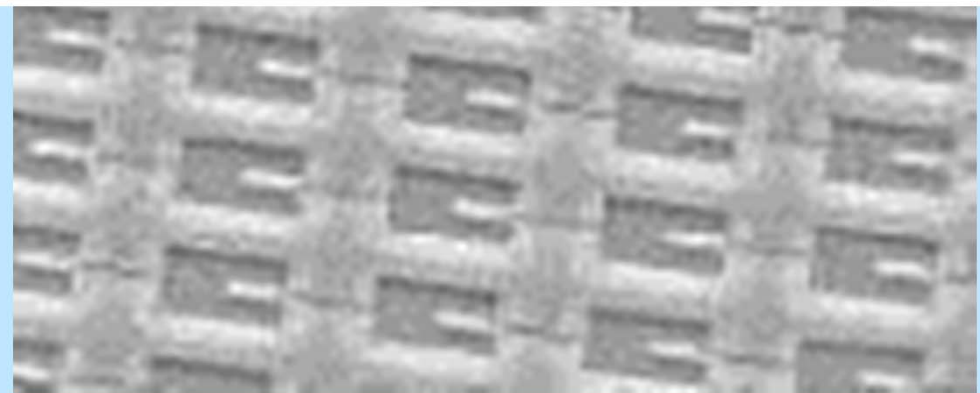
MEMS Device examples from the Platform

Multi gas sensor based on NEMS resonators

- GC column provides selectivity by separating in time and space the gas mixture components
- NEMS detectors sequentially detect the elution peaks at the GC output



Both GC column and NEMS detectors can be miniaturized and fabricated with VLSI silicon micro- and nanofabrication techniques.





Access to Platform services

Platform Manager VTT

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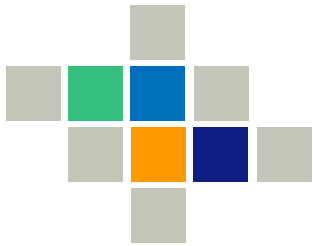
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Summary

- MEMS platform focused on SOI wafer technology was presented
- This service oriented and open one-stop shop for SOI MEMS processing, prototyping and small scale production has been established by the HTA Alliance.
- Platform composes of process equipment, steps, modules and needed personnel to run the facilities. Platform forms a basis for research and product development
- Benefits of the platform are:
 - Faster — because optimized use of existing process modules
 - Lower cost — because utilizing existing equipment base
 - Less risky — because wide base of expertise and solutions
 - More innovative solutions — because access to wider technology portfolio
 - Effective industrialization and production capability